



DMN3008SFG

30V N-CHANNEL ENHANCEMENT MODE MOSFET

PowerDI3333-8

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C
30V	4.4mΩ @ V _{GS} = 10V	62A
	5.5mΩ @ V _{GS} = 4.5V	56A

Description

This MOSFET is designed to minimize the on-state resistance $(R_{DS(ON)})$ and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

Applications

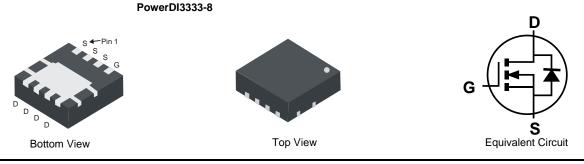
- Backlighting
- Power Management Functions
- DC-DC Converters

Features and Benefits

- Low R_{DS(ON)} Ensures On-State Losses are Minimized
- Small, Form Factor Thermally Efficient Package Enables Higher
 Density End Products
- Occupies only 33% of the Board Area Occupied by SO-8 Enabling Smaller End Products
- 100% Unclamped Inductive Switch (UIS) Test in Production
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: PowerDI[®]3333-8
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 🕄
- Weight: 0.072 grams (Approximate)



Ordering Information (Note 4)

Part Number	Case	Packaging		
DMN3008SFG-7	PowerDI3333-8	2,000/Tape & Reel		
DMN3008SFG-13	PowerDI3333-8	3,000/Tape & Reel		

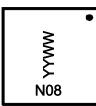
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.</p>

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

PowerDI3333-8



N08= Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 18 = 2018) WW = Week Code (01 to 53)

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Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage			V _{DSS}	30	V
Gate-Source Voltage			V _{GSS}	±20	V
Continuous Drain Current (Note 6) V _{GS} = 10V	Steady State	T _A = +25°C T _A = +70°C	ID	17.6 14.1	A
	t<10s	T _A = +25°C T _A = +70°C	ID	23.0 18.4	А
	Steady State	T _C = +25°C T _C = +70°C	I _D	62 50	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			IDM	150	А
Maximum Continuous Body Diode Forward Current (Note 6)			Is	2	A
Avalanche Current, L = 0.1mH			I _{AS}	45	A
Avalanche Energy, L = 0.1mH			E _{AS}	101	mJ

Thermal Characteristics ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Total Device Disation (Note 5)	T _A = +25°C	P	0.9	W	
Total Power Dissipation (Note 5)	T _A = +70°C	PD	0.6		
Thermal Desistance, Junction to Ambient (Note 5)	Steady State	D	134	°C/W	
Thermal Resistance, Junction to Ambient (Note 5)	t < 10s	R _{θJA}	79	°C/W	
Total Dower Dissinction (Note 6)	T _A = +25°C	D	2.1	W	
Total Power Dissipation (Note 6)	T _A = +70°C	PD	1.3		
Thermal Registeres, Junction to Ambient (Note 6)	Steady State	Р	58	°C/W	
Thermal Resistance, Junction to Ambient (Note 6)	t < 10s	R _{θJA}	34	°C/W	
Thermal Resistance, Junction to Case (Note 6)		R _{θJC}	4.8	°C/W	
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	30		_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	IDSS	_	_	10	μA	$V_{DS} = 30V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	1	—	2.3	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance		_	3.9	4.4	mΩ	$V_{GS} = 10V, I_D = 13.5A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	—	4.6	5.5	11122	V _{GS} = 4.5V, I _D = 13.5A	
Diode Forward Voltage	V _{SD}	_	0.75	1.2	V	$V_{GS} = 0V, I_S = 1A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	_	3,690	—	pF		
Output Capacitance	C _{oss}	—	530	—	рF	V _{DS} = 10V, V _{GS} = 0V, f = 1MHz	
Reverse Transfer Capacitance	Crss	—	459		pF		
Gate Resistance	Rg	_	0.9	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	41	_	nC		
Total Gate Charge (V _{GS} = 10V)	Qg	_	86	—	nC		
Gate-Source Charge	Q _{gs}	_	9.2	—	nC	$V_{DS} = 24V, I_D = 27A$	
Gate-Drain Charge	Q _{gd}	_	18.6	—	nC	1	
Turn-On Delay Time	t _{D(ON)}	_	5.7	—	ns		
Turn-On Rise Time	t _R	_	14.0	—	ns	$V_{DD} = 15V, V_{GS} = 10V,$ $R_{L} = 1.11\Omega, R_{g} = 4.7\Omega,$ $I_{D} = 13.5A$	
Turn-Off Delay Time	t _{D(OFF)}		63.7		ns		
Turn-Off Fall Time	t _F	—	28.4	—	ns		
Reverse Recovery Time	t _{RR}	_	19.3	—	ns		
Reverse Recovery Charge	Q _{RR}	—	10.7	—	nC	I _F =13.5A, di/dt=100A/µs	

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

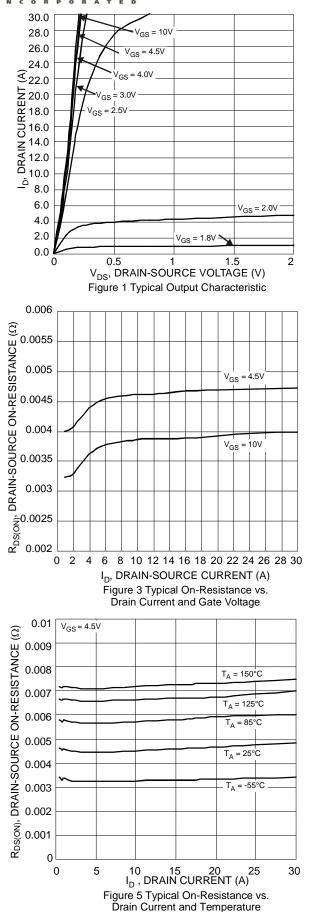
6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.







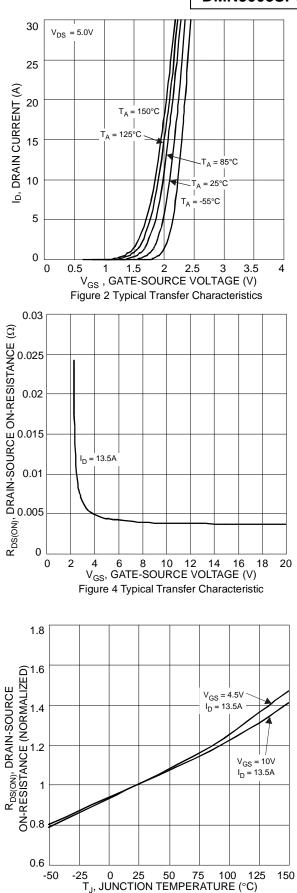
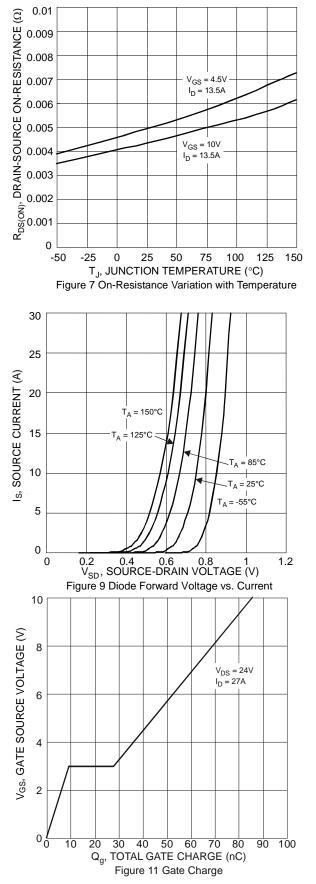
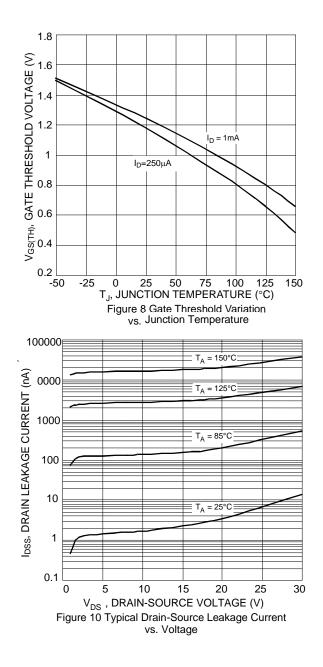


Figure 6 On-Resistance Variation with Temperature

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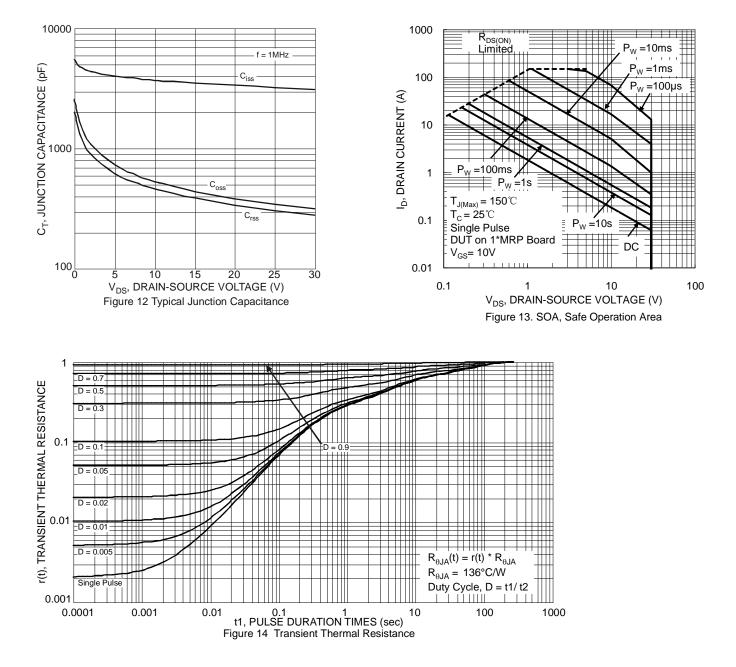




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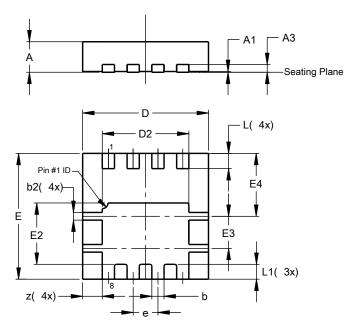
DMN3008SFG





Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

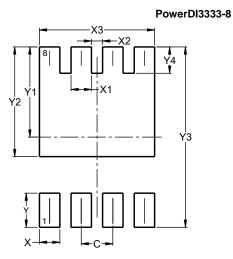


PowerDI3333-8					
Dim	Min	Max	Тур		
Α	0.75	0.85	0.80		
A1	0.00	0.05	0.02		
A3	-	-	0.203		
b	0.27	0.37	0.32		
b2	0.15	0.25	0.20		
D	3.25	3.35	3.30		
D2	2.22	2.32	2.27		
E	3.25	3.35	3.30		
E2	1.56	1.66	1.61		
E3	0.79	0.89	0.84		
E4	1.60	1.70	1.65		
е	-	-	0.65		
L	0.35	0.45	0.40		
L1	_	-	0.39		
z	_	-	0.515		
All Dimensions in mm					

PowerDI3333-8

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions Value (in mm) 0.650 С 0.420 Х X1 0.420 X2 0.230 Х3 2.370 0.700 Υ Y1 1.850 Y2 2.250 Y3 3.700 Y4 0.540



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